

# Low Voltage, Dual Supply, Low R<sub>ON</sub>, Quad SPST Analog Switches

### DESCRIPTION

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with  $\pm$  3 V to  $\pm$  6 V.

Combining high speed ( $t_{ON}$ : 42 ns), flat  $R_{DS(on)}$  over the analog signal range ( $\Omega$ ), minimal insertion lose (-3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the truth table. The DG9426 has two normally open and two normally closed switches.

### FEATURES

- 2.7 V thru 12 V single supply or  $\pm$  3 thru  $\pm$  6 dual supply
- On-resistance R<sub>DS(on)</sub>: 1.7 Ω
- Fast switching t<sub>ON</sub>: 42 ns - t<sub>OFF</sub>: 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- 2000 V ESD protection

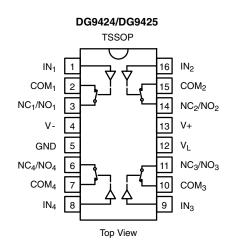
#### BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

### **APPLICATIONS**

- Automatic test equipment
- Data acquisition systems
- Communication systems
- ADC systems
- xDSL and PBX / PABX
- Audio signal routing

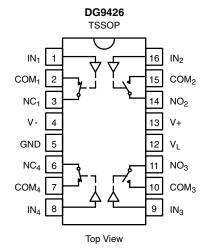
### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE							
LOGIC	DG9424	DG9425					
0	OFF	ON					
1	ON	OFF					



### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE							
LOGIC	SW <sub>1</sub> , SW <sub>4</sub>	SW <sub>2</sub> , SW <sub>3</sub>					
0	ON	OFF					
1	OFF	ON					

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER				
-40 °C to +85 °C		DG9424DQ-T1-E3				
	16-Pin TSSOP	DG9425DQ-T1-E3				
		DG9426DQ-T1-E3				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		LIMIT	UNIT			
V+ to V-		-0.3 to +13				
GND to V-	7					
VL		(GND - 0.3) to (V+) + 0.3	V			
IN, COM, NC, NO <sup>a</sup>		(V-) - 0.3 to (V+) + 0.3				
Continuous Current (NO, NC, COM Pins)		100	^			
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)		200	mA			
Storage Temperature		-65 to +150	°C			
Power Dissipation (Package) <sup>b</sup>		450	mW			
Thermal Resistance <sup>b</sup>	−−−− 16-Pin TSSOP °	178	°C/W			

Notes

a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 7 mW/°C above 25 °C.



DG9424, DG9425, DG9426

Vishay Siliconix

SPECIFICATIONS <sup>a</sup> Single Supply 12 V								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 12 V, V- = 0 V	TEMP. <sup>b</sup>	LIMITS -40 °C to +85 °C			UNIT	
		$V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. °	MAX. d		
Analog Switch								
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	V	
On-Resistance	R <sub>ON</sub>	V+ = 10.8 V, V- = 0 V	Room	-	1.8	3	Ω	
On hesistance	TION	$I_{\rm NO}, I_{\rm NC}$ = 50 mA, $V_{\rm COM}$ = 2 V / 9 V	Full	-	-	4	22	
Digital Control								
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.01	1	μA	
Dynamic Characteristics								
Turn-On Time <sup>e</sup>	+		Room	-	42	57		
	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Full	-	-	65	ns	
	+	$V_{NO}$ , $V_{NC} = 5$ V, see fig. 2	Room	-	28	42		
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>		Full	-	-	44		
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, V <sub>NO</sub> , V <sub>NC</sub> = 5 V R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35 pF	Room	2	-	-		
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 V, R_g = 0 \Omega, C_L = 1 nF$	Room	-	38	-	рС	
Off-Isolation <sup>e</sup>	OIRR	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF	Room	-	-56	-	dB	
Channel-to-Channel Crosstalk e	X <sub>TALK</sub>	f = 1 MHz	Room	-	-77	-	αв	
NO. NO. Off Consolitones 6	C <sub>NO(off)</sub>		Room	_	49			
NO, NC Off Capacitance <sup>e</sup>	C <sub>NC(off)</sub>	£ 1 MIL	RUUIII	-	49	-		
COM Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	37	-	pF	
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room	-	89	-		
Power Supplies								
Desitive Supply Current	l+		Room	-	0.02	1		
Positive Supply Current	1+		Full	-	-	5		
No poting Querche Quercet	1		Room	-1	-0.002	-		
Negative Supply Current	I-		Full	-5	-	-		
Logio Supply Current	I	$V_{IN} = 0 \text{ or } V_L$	Room	-	0.002	1	μA	
Logic Supply Current	ΙL		Full	-	-	5		
Cround Current	1		Room	-1	-0.002	-		
Ground Current	I <sub>GND</sub>		Full	-5	-	-		

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# DG9424, DG9425, DG9426

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SPECIFICATIONS <sup>a</sup> Dual Supply ± 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		LIMITS -40 °C to +85 °C			UNIT
	$V_{\rm L} = 5 V, V_{\rm IN} = 5 V$ $V_{\rm L} = 5 V, V_{\rm IN} = 2.4 V, 0.8 V^{\rm f}$	V+ = 5 V, V- = 5 V V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>		MIN. <sup>d</sup>	۲YP. ۵	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-5		5	V
On-Resistance	Р	V+ = 4.5 V, V- = -4.5 V	Room	-	2	3.3	0
On-Resistance	R <sub>ON</sub>	$I_{NO}$ , $I_{NC}$ = 50 mA, $V_{NO}$ , $V_{COM}$ = ± 3.5 V	Full	-	-	4.3	Ω
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current	I <sub>NC(off)</sub>	V+ = 5.5 V, V- = -5.5 V	Full	-10	-	10	
Switch On Leakage Guilent	<b>.</b>	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
	I <sub>COM(off)</sub>		Full	-10	-	10	
Channel On Leakage Current		V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
Channel On Leakage Ourrent	I <sub>COM(on)</sub>	$V_{NO}$ , $V_{NC} = V_{COM} = \pm 4.5 V$	Full	-10	-	10	
Digital Control							
Input Current <sup>a</sup>	$I_{\text{INL}}$ or $I_{\text{INH}}$		Full	-1	0.05	1	μA
Dynamic Characteristics				1	n	•	
Turn-On Time <sup>e</sup>	ton	t <sub>ON</sub> R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room	-	48	67	ns
	CIN		Full	-	-	81	
Turn-Off Time <sup>e</sup>	$V_{NO}, V_{NC} = \pm 3.5 \text{ V}, \text{ see fig. 2}$	$V_{NO}$ , $V_{NC} = \pm 3.5$ V, see fig. 2	Room	-	34	57	
	-011		Full	-	-	67	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, V <sub>NO</sub> , V <sub>NC</sub> = 3.5 V R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35 pF	Room	2	-	-	
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	112	-	рС
Off Isolation <sup>e</sup>	OIRR	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz	Room	-	-56	-	dB
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	$n_{L} = 50 \Omega_{2}, O_{L} = 5 \text{ pr}, T = T \text{ Minz}$	Room	-	-82	-	uв
Source Off Capacitance <sup>e</sup>	$\begin{array}{c} C_{NO(off)} \\ C_{NC(off)} \end{array}$		Room	-	38	-	
Drain Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>	f = 1 MHz	Room	-	38	-	pF
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room	-	89	-	
Power Supplies							
Positive Supply Current <sup>e</sup>	I+		Room	-	0.03	1	
			Full	-	-	5	
Negative Supply Current <sup>e</sup>	I-		Room	-1	-0.002	-	
		$V_{IN} = 0 \text{ or } V_L$	Full	-5	-	-	μA
Logic Supply Current <sup>e</sup>	١L		Room	-	0.002	1	
	_		Full	-	-	5	
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room	-1	-0.002	-	
			Full	-5	-	-	

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# DG9424, DG9425, DG9426

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SPECIFICATIONS <sup>a</sup> Single Supply 5 V							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. <sup>b</sup>	LIMITS -40 °C to +85 °C			UNIT
		V+=5 V, V-=0 V $V_{L}=5 V, V_{IN}=2.4 V, 0.8 V f$		MIN. <sup>d</sup>	TYP. °	MAX. d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-	-	5	٧
On-Resistance <sup>e</sup>	R <sub>ON</sub>	$V_{+} = 4.5 V$ , $I_{NO}$ , $I_{NC} = 50 mA$ ,	Room	-	3.4	4.8	Ω
On-nesistance *	NON	VCOM = 1 V, 3.5 V	Full	-	-	5.8	52
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	t <sub>ON</sub>		Room	-	71	86	
	NOV	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Hot	-	-	106	
Turn-Off Time <sup>e</sup>	$V_{NO}$ , $V_{NC}$ = 3.5 V, see fig. 2	Room	-	37	51	ns	
			Hot	-	-	56	
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 only, V <sub>NO</sub> , V <sub>NC</sub> = 3.5 V R <sub>L</sub> = 300 $\Omega,$ C <sub>L</sub> = 35 pF	Room	5	-	-	
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	10	-	рС
Power Supplies							
Positive Supply Current <sup>e</sup>	l+		Room	-	0.02	1	
	It		Hot	-	-	5	
Negative Supply Current <sup>e</sup>	I-		Room	-1	-0.002	-	
Negative Supply Ourient	I-	$V_{IN} = 0$ or $V_{I}$	Hot	-5	-	-	μA
Logic Supply Current <sup>e</sup>	١L		Room	-	0.002	1	μΑ
	чL		Hot	-	-	5	
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room	-1	-0.002	-	
	GND		Hot	-5	-	-	

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# DG9424, DG9425, DG9426

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SPECIFICATIONS <sup>a</sup> Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. <sup>b</sup>	LIMITS -40 °C to +85 °C			UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. <sup>d</sup>	TYP. °	MAX. d	•••••
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	3	V
On-Resistance	R <sub>ON</sub>	V+ = 2.7 V, V- = 0 V	Room	-	8	13.8	Ω
	HON	$I_{NO}$ , $I_{NC}$ = 5 mA, $V_{COM}$ = 0.5 V, 2.2 V	Full	-	-	15.1	32
	I <sub>NO(off)</sub>		Room	-1	-	1	
Switch Off Leakage Current a	I <sub>NC(off)</sub>	V+ = 3.3 V, V- = 0 V	Full	-10	-	10	
Owner on Leakage Ourient		$V_{COM} = 0.3 \text{ V}, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA
	I <sub>COM(off)</sub>		Full	-10	-	10	
Channel On Leakage Current <sup>a</sup>		V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	
Channel On Leakage Guilent	I <sub>COM(on)</sub>	$V_{NO}$ , $V_{NC} = V_{COM} = 0.3$ V, 3 V		-10	-	10	
Digital Control <sup>e</sup>							
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.005	1	μA
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>		Room	-	140	163	
	UN	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Full	-	-	193	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC}$ = 1.5 V, see fig. 2	Room	-	65	80	ns
	<b>'OFF</b>		Full	-	-	89	
Break-Before-Make Time Delay	t <sub>D</sub>	DG9426 only, V <sub>NO</sub> , V <sub>NC</sub> = 1.5 V $R_L$ = 300 $\Omega$ , C <sub>L</sub> = 35 pF	Room	5			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g$ = 0 V, $R_g$ = 0 $\Omega$ , $C_L$ = 1 nF	Room	-	15	-	рС
Off Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$	Room	-	-56	-	dB
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	f = 1 MHz	Room	-	-80	-	uБ
Source Off Capacitance <sup>e</sup>	C <sub>NO(off)</sub>		Room	-	53	_	- pF
	C <sub>NC(off)</sub>	f = 1 MHz	noom	-	55		
Drain Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>		Room	-	42	-	μг
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room	-	92	-	

Notes

a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.

b. Room = 25 °C, Full = As determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

e. Guaranteed by design, not subject to production test.

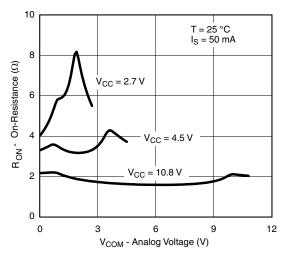
f. V<sub>IN</sub> = Input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

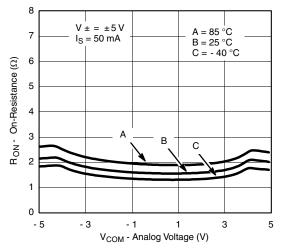
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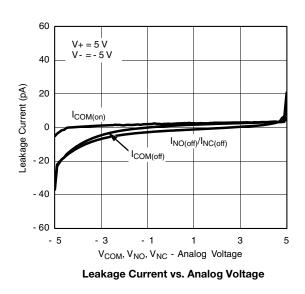
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

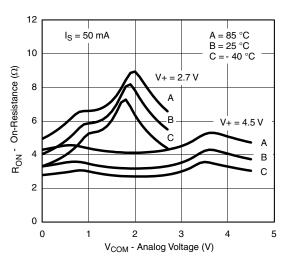


R<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage

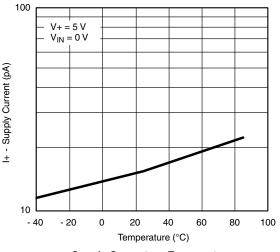


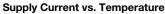
R<sub>ON</sub> vs. Analog Voltage and Temperature

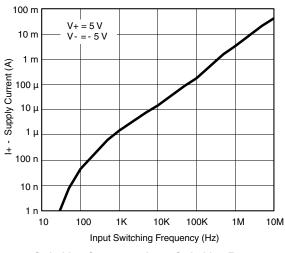




R<sub>ON</sub> vs. Analog Voltage and Temperature







Switching Current vs. Input Switching Frequency

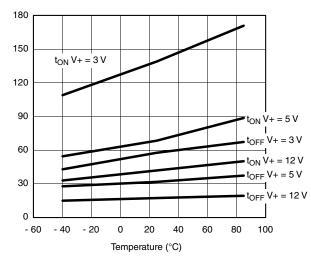
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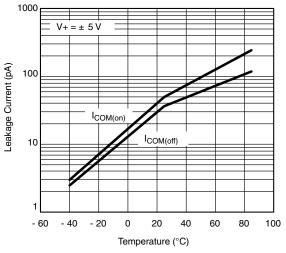
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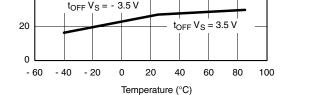
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Switching Time vs. Temperature and Single Supply Voltage



Leakage Current vs. Temperature



120

100

80

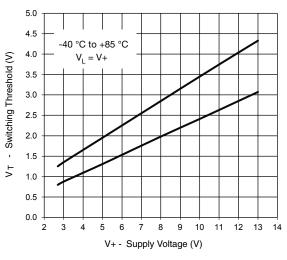
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40

 $V_{\text{SUPPLY}} = \pm 5 \text{ V}$ 

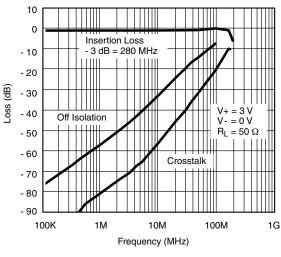
 $t_{ON} V_{S} = -3.5 V$ 

Switching Time vs. Temperature and Dual Supply Voltage



Switching Threshold vs. Supply Voltage

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Insertion Loss, Off Isolation and Crosstalk vs. Frequency

DG9424, DG9425, DG9426

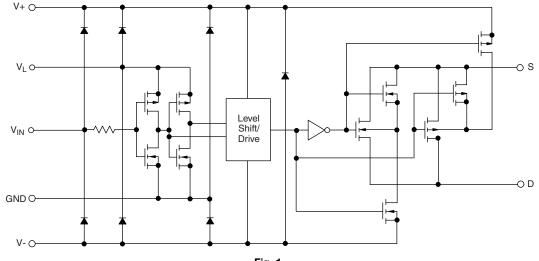
t<sub>ON</sub> V<sub>S</sub> = 3.5 V

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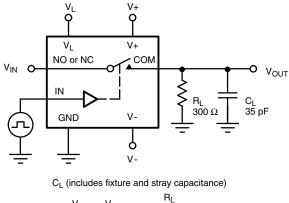


### SCHEMATIC DIAGRAM (typical channel)

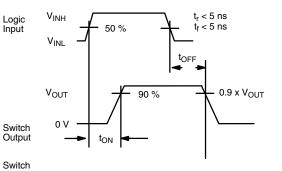




### **TEST CIRCUITS**

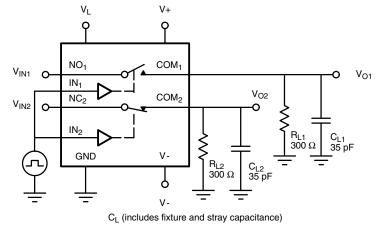


 $V_{OUT} = V_{IN}$   $R_L + r_{ON}$ 



Note: Logic input waveform is inverted for switches that have the opposite logic sense control





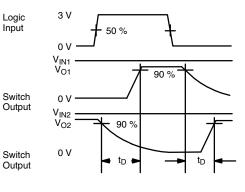


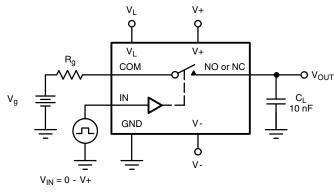
Fig. 3 - Break-Before-Make (DG9426)

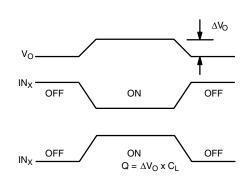
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### **TEST CIRCUITS**





 $\ensuremath{\text{IN}_{\text{X}}}$  dependent on switch configuration Input polarity determined by sense of switch.

#### Fig. 4 - Charge Injection

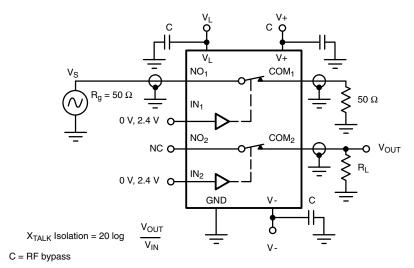
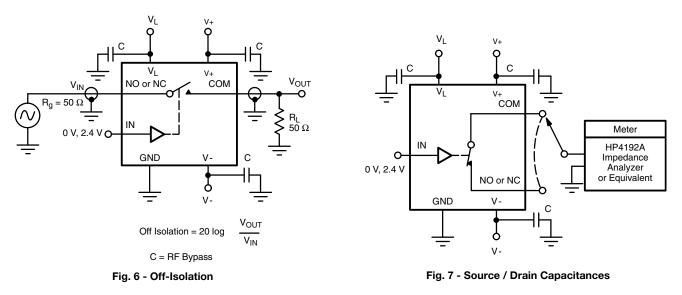


Fig. 5 - Crosstalk



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg271807">www.vishay.com/ppg271807</a>.

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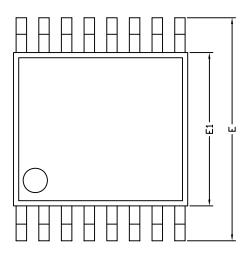
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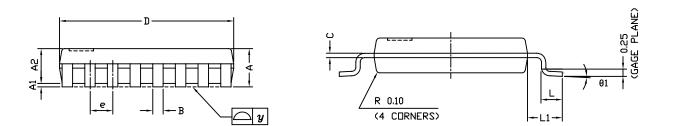


# Package Information

Vishay Siliconix

### TSSOP: 16-LEAD





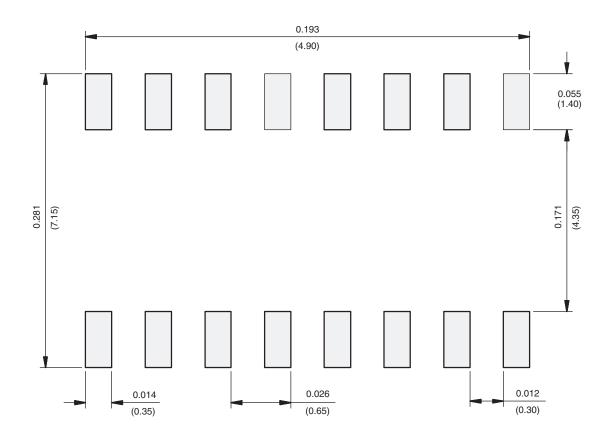
	DIMENSIONS IN MILLIMETERS						
Symbols	Min	Nom	Мах				
A	-	1.10	1.20				
A1	0.05	0.10	0.15				
A2	-	1.00	1.05				
В	0.22	0.28	0.38				
С	-	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	-	-	0.10				
θ1	0°	3°	6°				
ECN: S-61920-Rev. D, 23 DWG: 5624	-Oct-06						



**PAD** Pattern

Vishay Siliconix

### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



Vishay

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